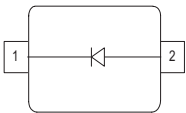


Silicon Tuning Diode

- High Q hyperabrupt tuning diode
- Very low capacitance spread
- Designed for low tuning voltage operation for VCO's in mobile communications equipment
- For low frequency control elements such as TCXOS and VCXOS
- High capacitance ratio and good C-V linearity
- Pb-free (RoHS compliant) package


BBY65-02V


Type	Package	Configuration	L_S (nH)	Marking
BBY65-02V	SC79	single	0.6	F

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

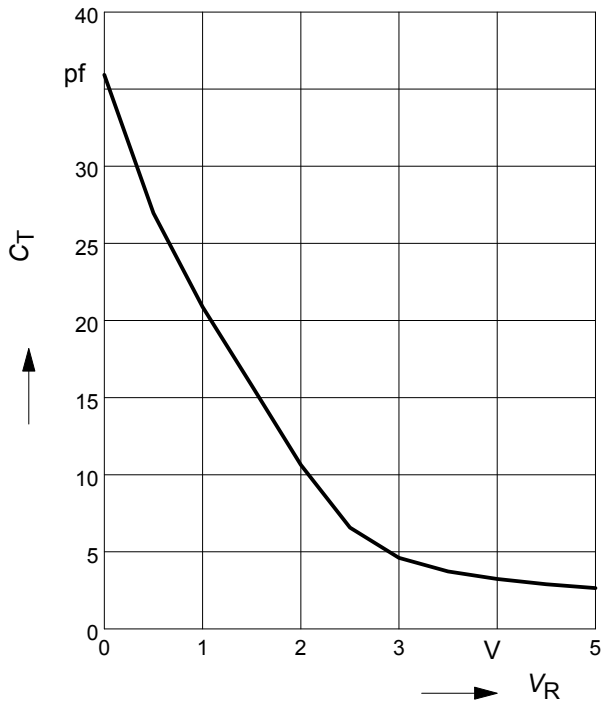
Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	15	V
Forward current	I_F	50	mA
Operating temperature range	T_{op}	-55 ... 150	°C
Storage temperature	T_{stg}	-55 ... 150	

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current	I_R				nA
$V_R = 10\text{ V}$		-	-	10	
$V_R = 10\text{ V}, T_A = 85^\circ\text{C}$		-	-	100	
AC Characteristics					
Diode capacitance	C_T				pF
$V_R = 0.3\text{ V}, f = 1\text{ MHz}$		28.2	29.5	30.8	
$V_R = 1\text{ V}, f = 1\text{ MHz}$		-	20.25	-	
$V_R = 2\text{ V}, f = 1\text{ MHz}$		-	9.8	-	
$V_R = 3\text{ V}, f = 1\text{ MHz}$		-	4.45	-	
$V_R = 4.7\text{ V}, f = 1\text{ MHz}$		2.6	2.7	2.8	
Capacitance ratio	$C_{T0.3}/C_{T4.7}$	10	10.9	-	pF
$V_R = 0.3\text{ V}, V_R = 4.7\text{ V}$					
Capacitance ratio	C_{T1}/C_{T3}	-	4.55	-	pF
$V_R = 1\text{ V}, V_R = 3\text{ V}$					
Series resistance	r_S	-	0.6	0.9	Ω
$V_R = 1\text{ V}, f = 470\text{ MHz}$					

Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



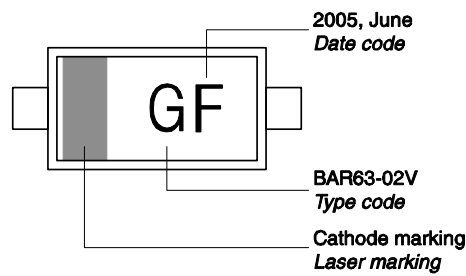
Package Outline



Foot Print

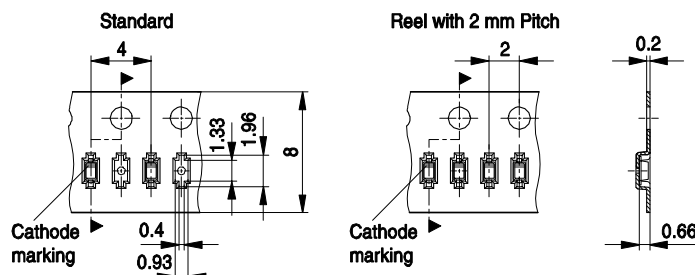


Marking Layout (Example)



Standard Packing

- Reel ø180 mm = 3.000 Pieces/Reel
- Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)
- Reel ø330 mm = 10.000 Pieces/Reel



Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

Edition 2009-11-16

**Published by
Infineon Technologies AG
81726 Munich, Germany**

**© 2009 Infineon Technologies AG
All Rights Reserved.**

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Infineon\(英飞凌\)](#)